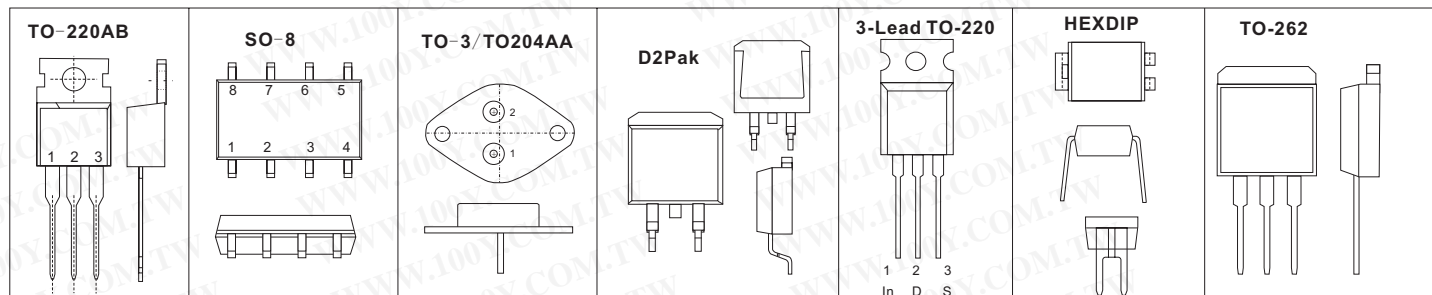


# 二极管+电晶体+模块

## IR~系列功率场效电晶体

详细产品规格 - 请点击 [cn.100y.com.tw](http://cn.100y.com.tw)



100Y 编号	厂商编号	制造厂商	说明	N/P Ch.	Pin/Packag e	Id(max.) A	Rds(on)(max.) Ω	Pd(max.) W	Vdss(max.) V
24804	IRF9140	Intersil	POWER MOSFET	P-Ch.	TO-204AA	-19A	0.2Ω	125W	-100V
34036	IRF9540N	IR	HEXFET Power MOSFET	P	TO-220AB	-23A	0.117Ω	140W	-100V
16192	IRF9540N	IR	Power MOSFET 【无铅】	P-Ch.	3P/TO-220 AB	19A	0.2Ω	150W	100V
34037	IRF9540NS	IR	P-Channel Power MOSFET	P	D2Pak	-23A	0.117Ω	140W	-100V
19634	IRF9540S	IR	Surface Mount Power MOSFET	P-Ch.	TO-263(D2 Pak)	-19A	0.2Ω	150	-100V
29965	IRF9610	IR	Power MOSFET	P-Ch.	3P/TO-220 AB	-1.8A	3.0Ω	20W	-200V
34038	IRF9620	IR	HEXFET Power MOSFET	P	TO-220AB	-3.5A	1.5Ω	40W	-200V
15668	IRF9630PBF	IR	Advanced Power MOSFET	P-Ch.	3P/TO-220 AB	-6.5A	0.8Ω	74W	-200V
19614	IRF9630S	IR	Surface Mount Power MOSFET	P Ch.	TO-263(D2 Pak)	6.5A	0.8Ω	74W	-200V
17946	IRF9640PBF	IR	Power MOSFET	P-Ch.	3P/TO-220 AB	-11A	0.5Ω	125W	-200V
34039	IRF9952	IR	HEXFET Power MOSFET	N and P Ch	SO-8	3.5A N-Ch/-2.3A P-Ch	0.10Ω N-Ch/0.25Ω P-Ch	2.0W	30V N-Ch/-30V P-Ch
34040	IRF9953	IR	HEXFET Power MOSFET	P	SO-8	-2.3A	0.25Ω	2.0W	-30V
34042	IRF9Z14	IR	HEXFET Power MOSFET	P	TO-220AB	-6.7A	0.50Ω	43W	-60V
34043	IRF9Z24N	IR	HEXFET Power MOSFET	P	TO-220AB	-12A	0.175Ω	45W	-55V
19643	IRF9Z24NS	IR	SMD Power MOSFET	P-Ch.	TO-263	-12A	0.175Ω	45W	-55V
16484	IRF9Z34N	IR	P-channel MOSFET	P-Ch.	3P/TO-220	19A	0.1Ω	68W	-55V
34044	IRF9Z34S	IR	HEXFET Power MOSFET	P	D2Pak	-18A	0.14Ω	88W	-60V
34046	IRFB11N50A	IR	HEXFET Power MOSFET	N	TO-220AB	11A	0.52Ω	170W	500V
34047	IRFB31N20D	IR	HEXFET Power MOSFET	N	TO-220AB	31A	0.082Ω	200W	200V
39759	IRFB4310	IR	HEXFET Power MOSFET	N	TO-220AB	140A	7.0mΩ	330W	100V
34049	IRFB59N10D	IR	HEXFET Power MOSFET	N	TO-220AB	59A	0.025Ω	200W	100V
34050	IRFB9N30A	IR	HEXFET Power MOSFET	N	TO-220AB	9.3A	0.45Ω	96W	300V
34051	IRFB9N60A	IR	HEXFET Power MOSFET	N	TO-220AB	9.2A	0.75Ω	170W	600V
34052	IRFB9N65A	IR	HEXFET Power MOSFET	N	TO-220AB	8.5A	0.93Ω	167W	650V
34056	IRFBC20	IR	HEXFET Power MOSFET	N	TO-220AB	2.2A	4.4Ω	50W	600V
17949	IRFBC30	IR	Power MOSFET	N	3P/TO-220 AB	3.6A	1.8Ω	75W	600V
34058	IRFBC30L	IR	HEXFET Power MOSFET	N	TO-262	3.6A	2.2Ω	74W	600V
34060	IRFBC40A	IR	HEXFET Power MOSFET	N	TO-220AB	6.2A	1.2Ω	125 W	600V
34061	IRFBC40L	IR	HEXFET Power MOSFET	N	TO-262	6.2A	1.2Ω	130 W	600V
34062	IRFBC40LC	IR	Power MOSFET	N	TO-220AB	6.2A	1.2Ω	125W	600V
17950	IRFBC40PBF	IR	Power MOSFET	N	3P/TO-220 AB	6.2A	1.0Ω	125W	600V
34064	IRFBE20	IR	Power MOSFET	N	TO-220 AB	1.8A	6.5Ω	54W	800V
16296	IRFBE30	IR	Power MOSFET	N-Ch.	3P/TO-220	4.1A	3Ω	125W	800V
34065	IRFBF20	IR	HEXFET Power MOSFET	N	TO-220AB	1.7A	8.0Ω	54W	900V
34067	IRFBF30	IR	HEXFET Power MOSFET	N	TO-220AB	3.6A	3.7Ω	125W	900V
34068	IRFBG20	IR	HEXFET Power MOSFET	N	TO-220AB	1.4A	11Ω	54W	1000V
12298	IRFBG30	IR	HEXFET 1000V 3.1A N-Channel	N-Ch.	3P/TO-220 AB	3.1A	5Ω	125W	1000V
26489	IRFD014	IR	4-Pins DIL P Ch. 60Vds Rds:0.28Ω Idm:13A	P-Ch.	4P/DIP	1.7A	0.20Ω	1.3W	60V
33689	IRFD024	IR	Power MOSFET(Vdss=60V, Rds(on)=0.10ohm, Id=2.5A)		4P/DIP	2.5A	0.10 Ω	1.3W	60V
34069	IRFD110	IR	Power MOSFET	N	4P/DIP	1.0A	0.54Ω	1.3W	100V
34070	IRFD120	IR	Power MOSFET	N	4P/DIP	1.3A	0.27Ω	1.3W	100V
34072	IRFD210	IR	Power MOSFET	N	4P/DIP	0.60A	1.5Ω	1.0W	200V
34073	IRFD220	IR	Power MOSFET	N	4P/DIP	0.80A	0.80Ω	1.0W	200V
26488	IRFD9014	IR	4-Pins DIL P Ch. 60Vds Rds:0.28Ω Idm:13A	P-Ch.	4P/DIP	-8.8A	0.50Ω	1.3W	-60V
12276	IRFD9024	IR	4-Pins DIL P Ch. 60Vds Rds:0.28Ω Idm:13A	P-Ch.	4P/DIP	-13A	0.28Ω	1.3W	-60V
34074	IRFD9110	IR	Power MOSFET	P	4-Pins DIL	-0.70A	1.2Ω	1.3W	-100V
34075	IRFD9120	IR	Power MOSFET	P	4P/DIP	-1.0A	0.60Ω	1.3W	-100V



服务专线: 台湾: 886-3-5753170  
 传 真: 台湾: 886-3-5753172  
 E-mail: 台湾: sale@100y.com.tw

深圳: 86-755-83298787  
 深圳: 86-755-83640655  
 深圳: 100y@163.com

上海: 86-21-34970699  
 上海: 86-21-64605107  
 上海: 100y-1@163.com